## 1. General description

PNP/PNP matched double transistor in an ultra small Surface-Mounted Device (SMD) plastic package. The transistors in the SOT666 package are fully isolated internally.

PNP/PNP hFE1/hFE2 0.98 complement: PMP5201V

NPN/NPN complement: PMP4501V

### 2. Features and benefits

- Current gain matching
- Base-emitter voltage matching
- Application-optimized pinout

## 3. Applications

- · Current mirror
- · Differential amplifier

### 4. Quick reference data

#### Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per transist	or					<u> </u>
$V_{CEO}$	collector-emitter voltage	open base	-	-	-45	V
Ic	collector current		-	-	-100	mA
h <sub>FE</sub>	DC current gain	V <sub>CE</sub> = -5 V; I <sub>C</sub> = -2 mA; T <sub>amb</sub> = 25 °C	200	290	450	
Per device						
h <sub>FE1</sub> /h <sub>FE2</sub>	DC current gain matching	$V_{CE} = -5 \text{ V}; I_{C} = -2 \text{ mA}; T_{amb} = 25 \text{ °C}$	0.95	1	-	
V <sub>BE1</sub> -V <sub>BE2</sub>	base-emitter voltage matching		-	-	2	mV



### 45 V, 100 mA PNP/PNP matched double transistor

# 5. Pinning information

#### **Table 2. Pinning information**

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	B1	base TR1	6 5 4	04 54 50
2	B2	base TR2		C1 E1 E2
3	C2	collector TR2		TR2
4	E2	emitter TR2	0	
5	E1	emitter TR1	1 2 3	B1 B2 C2 006aaa550
6	C1	collector TR1	SOT666	

# 6. Ordering information

#### **Table 3. Ordering information**

Type number	Package						
	Name	Description	Version				
PMP5501V		plastic, surface-mounted package; 6 leads; 0.5 mm pitch; 1.6 mm x 1.2 mm x 0.55 mm body	<u>SOT666</u>				

## 7. Marking

#### Table 4. Marking codes

Type number	Marking code
PMP5501V	ED

# 8. Limiting values

### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
Per transiste	or					
V <sub>CBO</sub>	collector-base voltage	open emitter		-	-50	V
V <sub>CEO</sub>	collector-emitter voltage	open base		-	-45	V
V <sub>EBO</sub>	emitter-base voltage	open collector		-	-5	V
I <sub>C</sub>	collector current			-	-100	mA
I <sub>CM</sub>	peak collector current	single pulse; t <sub>p</sub> ≤ 1 ms		-	-200	mA
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[1] [2]	-	200	mW
Per device						
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[1] [2]	-	300	mW
Tj	junction temperature			-	150	°C
T <sub>amb</sub>	ambient temperature			-65	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C

<sup>[1]</sup> Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

<sup>[2]</sup> Reflow soldering is the only recommended soldering method.

#### 45 V, 100 mA PNP/PNP matched double transistor

## 9. Thermal characteristics

#### **Table 6. Thermal characteristics**

Symbol	Parameter	Conditions		Min	Тур	Max	Unit		
Per transistor	Per transistor								
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1] [2]	-	-	625	K/W		
Per device									
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1] [2]	-	-	416	K/W		

<sup>[1]</sup> Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

### 10. Characteristics

**Table 7. Characteristics** 

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transisto	r						
I <sub>CBO</sub>	collector-base cut-off	V <sub>CB</sub> = -30 V; I <sub>E</sub> = 0 A; T <sub>amb</sub> = 25 °C		-	-	-15	nA
	current	V <sub>CB</sub> = -30 V; I <sub>E</sub> = 0 A; T <sub>j</sub> = 150 °C		-	-	-5	μA
I <sub>EBO</sub>	emitter-base cut-off current	V <sub>EB</sub> = -5 V; I <sub>C</sub> = 0 A; T <sub>amb</sub> = 25 °C		-	-	-100	nA
h <sub>FE</sub>	DC current gain	V <sub>CE</sub> = -5 V; I <sub>C</sub> = -10 μA; T <sub>amb</sub> = 25 °C		-	250	-	
		V <sub>CE</sub> = -5 V; I <sub>C</sub> = -2 mA; T <sub>amb</sub> = 25 °C		200	290	450	
V <sub>CEsat</sub>	collector-emitter	$I_C$ = -10 mA; $I_B$ = -0.5 mA; $T_{amb}$ = 25 °C		-	-50	-200	mV
	saturation voltage	$I_C$ = -100 mA; $I_B$ = -5 mA; $T_{amb}$ = 25 °C		-	-200	-400	mV
V <sub>BEsat</sub>	base-emitter saturation	$I_C$ = -10 mA; $I_B$ = -0.5 mA; $T_{amb}$ = 25 °C	[1]	-	-760	-	mV
VC	voltage	$I_C$ = -100 mA; $I_B$ = -5 mA; $T_{amb}$ = 25 °C	[1]	-	-920	-	mV
$V_{BE}$	base-emitter voltage	$V_{CE}$ = -5 V; $I_{C}$ = -2 mA; $T_{amb}$ = 25 °C	[2]	-600	-650	-700	mV
		V <sub>CE</sub> = -5 V; I <sub>C</sub> = -10 mA	[2]	-	-	-760	mV
C <sub>c</sub>	collector capacitance	V <sub>CB</sub> = -10 V; I <sub>E</sub> = 0 A; i <sub>e</sub> = 0 A; f = 1 MHz; T <sub>amb</sub> = 25 °C		-	-	2.2	pF
C <sub>e</sub>	emitter capacitance	$V_{EB}$ = -0.5 V; $I_{C}$ = 0 A; $i_{c}$ = 0 A; $f$ = 1 MHz; $T_{amb}$ = 25 °C		-	10	-	pF
f <sub>T</sub>	transition frequency	$V_{CE}$ = -5 V; $I_{C}$ = -10 mA; f = 100 MHz; $T_{amb}$ = 25 °C		100	175	-	MHz
NF	noise figure	$V_{CE}$ = -5 V; $I_{C}$ = -0.2 mA; $R_{S}$ = 2 k $\Omega$ ; $f$ = 10 Hz to 15.7 kHz; $T_{amb}$ = 25 °C		-	1.6	-	dB
		$V_{CE}$ = -5 V; $I_{C}$ = -0.2 mA; $R_{S}$ = 2 k $\Omega$ ; $f$ = 1 kHz; $B$ = 200 Hz		-	3.1	-	dB
Per device	<u>'</u>		-		-		
h <sub>FE1</sub> /h <sub>FE2</sub>	DC current gain matching	$V_{CE}$ = -5 V; $I_{C}$ = -2 mA; $T_{amb}$ = 25 °C		0.95	1	-	
V <sub>BE1</sub> -V <sub>BE2</sub>	base-emitter voltage matching			-	-	2	mV

<sup>[1]</sup>  $V_{BEsat}$  decreases by about 1.7 mV/K with increasing temperature.

PMP5501V

<sup>[2]</sup> Reflow soldering is the only recommended soldering method.

<sup>[2]</sup> V<sub>BE</sub> decreases by about 2 mV/K with increasing temperature.

### 45 V, 100 mA PNP/PNP matched double transistor

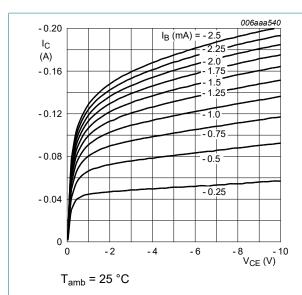
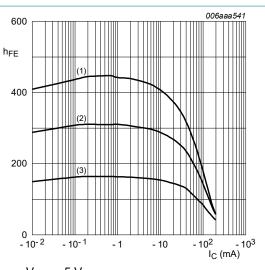
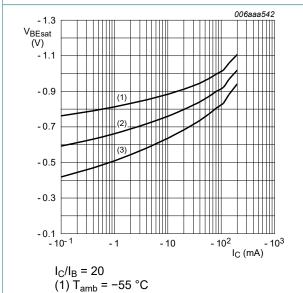


Fig. 1. Per transistor: Collector current as a function of collector-emitter voltage; typical values



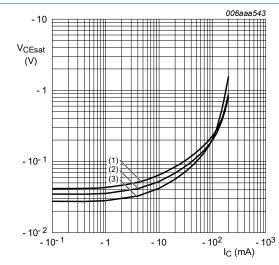
V<sub>CE</sub> = -5 V (1) T<sub>amb</sub> = 100 °C (2) T<sub>amb</sub> = 25 °C (3) T<sub>amb</sub> = -55 °C

Per transistor: DC current gain as a function of Fig. 2. collector current; typical values



(2) T<sub>amb</sub> = 25 °C (3)  $T_{amb} = 100 \, ^{\circ}C$ 

Fig. 3. Per transistor: Base-emitter saturation voltage as a function of collector current; typical values



 $I_{\rm C}/I_{\rm B} = 20$ (1)  $T_{amb}$  = 100 °C (2)  $T_{amb} = 25 \, ^{\circ}C$ (3)  $T_{amb} = -55 \, ^{\circ}C$ 

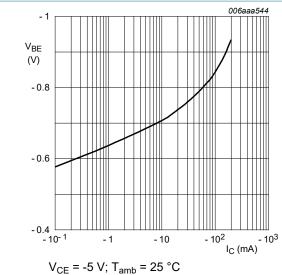
Fig. 4. Per transistor: Collector-emitter saturation voltage as a function of collector current; typical values

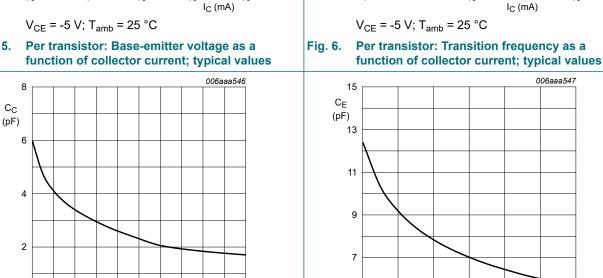
10<sup>3</sup>

fΤ (MHz)

10<sup>2</sup>

### 45 V, 100 mA PNP/PNP matched double transistor





-8 -10 V<sub>CB</sub> (V)

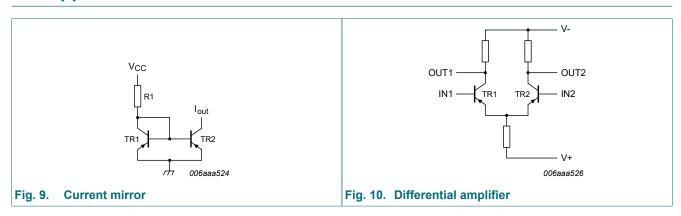
Per transistor: Collector capacitance as a function of collector-base voltage; typical values

Fig. 8. Per transistor: Emitter capacitance as a function of emitter-base voltage; typical values

 $f = 1 \text{ MHz}; T_{amb} = 25 \text{ °C}$ 

# 11. Application information

 $f = 1 \text{ MHz}; T_{amb} = 25 \text{ °C}$ 



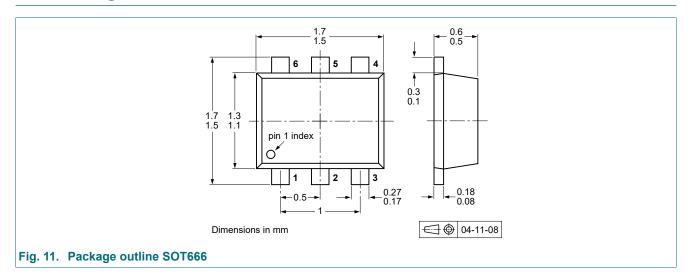
- 10<sup>2</sup>

006aaa547

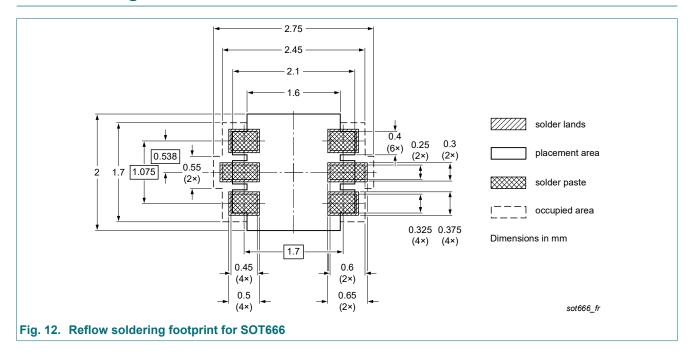
V<sub>EB</sub> (V)

45 V, 100 mA PNP/PNP matched double transistor

# 12. Package outline



## 13. Soldering



### 45 V, 100 mA PNP/PNP matched double transistor

# 14. Revision history

#### **Table 8. Revision history**

Tubio of Itorioion inot	7					
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes		
PMP5501V v.4	20221228	Product data sheet	-	PMP5501V_G_Y_3		
Modifications:	<ul> <li>The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia.</li> <li>Legal texts have been adapted to the new company name where appropriate.</li> <li>Family data sheet splitted to single type data sheets.</li> <li>Packing information removed.</li> <li>Product(s) changed to non-automotive qualification.</li> </ul>					
PMP5501V_G_Y_3	20090828	Product data sheet	-	PMP5501V_G_Y_2		
PMP5501V_G_Y_2	20060919	Product data sheet	-	PMP5501G_Y_1		
PMP5501G_Y_1	20060221	Product data sheet	-	-		

### 15. Legal information

#### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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PMP5501V

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### 45 V, 100 mA PNP/PNP matched double transistor

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